

Switching Diode

- Pb-Free Package is available.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Package	Shipping
LBAS16LT1	A6	SOT-23	3000/Tape&Reel
LBAS16LT1G	A6 (Pb-Free)	SOT-23	3000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	75	Vdc
Peak Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Reverse Voltage Leakage Current ($V_R = 75\text{Vdc}$)	I_R	—	1.0	μAdc
($V_R = 75\text{Vdc}, T_J = 150^\circ\text{C}$)		—	50	
($V_R = 25\text{Vdc}, T_J = 150^\circ\text{C}$)		—	30	
Reverse Breakdown Voltage ($I_{BR} = 100\mu\text{Adc}$)	$V_{(BR)}$	75	—	Vdc
Forward Voltage ($I_F = 1.0\text{mAdc}$)	V_F	—	715	mV
($I_F = 10\text{mAdc}$)		—	855	
($I_F = 50\text{mAdc}$)		—	1000	
($I_F = 150\text{mAdc}$)		—	1250	
Diode Capacitance ($V_R = 0, f = 1.0\text{MHz}$)	C_D	—	2.0	pF
Forward Recovery Voltage ($I_F = 10\text{mAdc}, t_r = 20\text{ns}$)	V_{FR}	—	1.75	Vdc
Reverse Recovery Time ($I_F = I_R = 10\text{mAdc}, R_L = 50\Omega$)	t_{rr}	—	6.0	ns
Stored Charge ($I_F = 10\text{mAdc}$ to $V_R = 5.0\text{Vdc}, R_L = 500\Omega$)	Q_S	—	45	pC

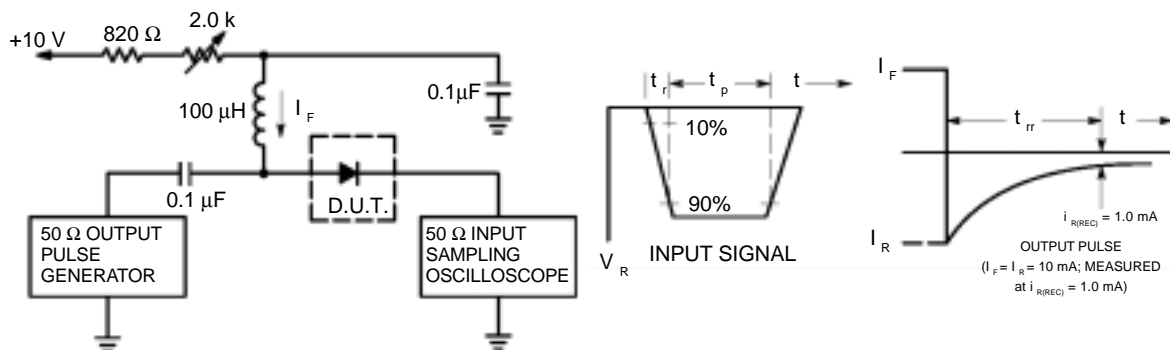
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

LBAS16LT1

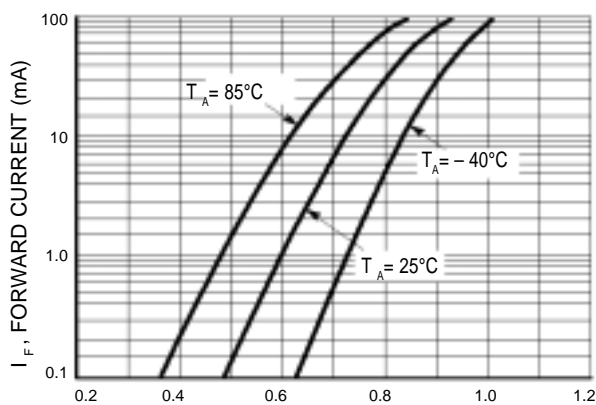


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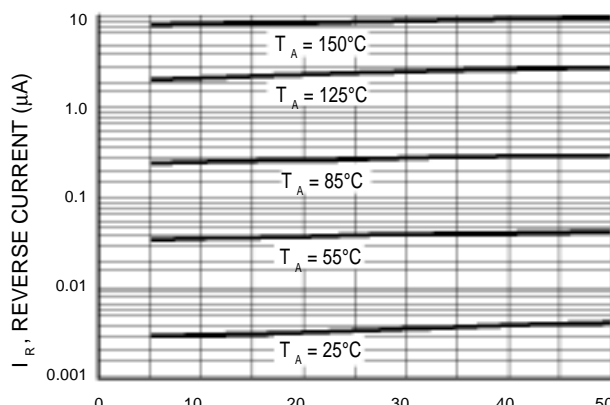
- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
 2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10 mA.
 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit



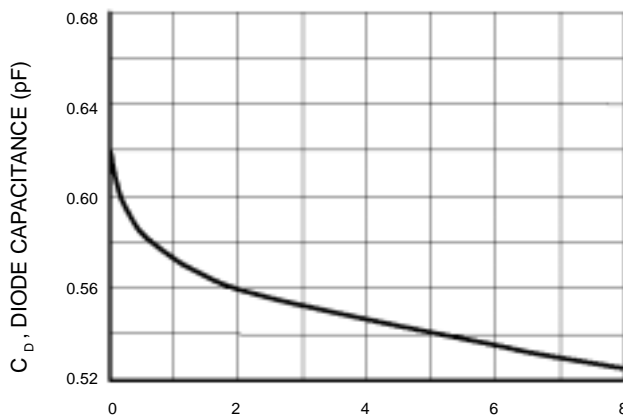
V_F , FORWARD VOLTAGE (VOLTS)

Figure 2. Forward Voltage



V_R , REVERSE VOLTAGE (VOLTS)

Figure 3. Leakage Current

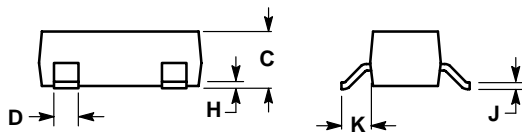
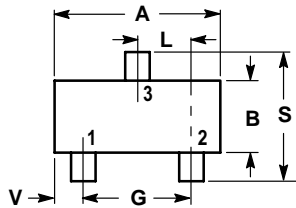


V_R , REVERSE VOLTAGE (VOLTS)

Figure 4. Capacitance

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SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. ANODE
 2. NO CONNECTION
 3. CATHODE

